

JST131U-800DS 1A TRIAC

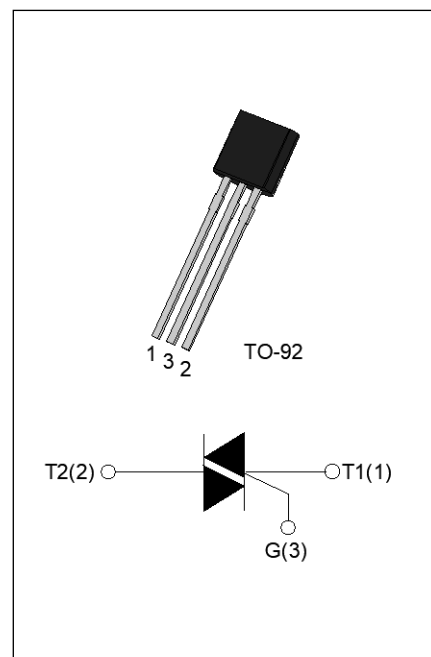
Rev.A.2.0

DESCRIPTION:

The JST131U-800DS triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. Complying with UL standards (File ref: E252906). Package TO-92 is RoHS compliant.

MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	1	A
V_{DRM}/V_{RRM}	800	V
$I_{GT\ I}/II/III/IV$	5/5/5/10	mA


ABSOLUTE MAXIMUM RATINGS

Parameter		Symbol	Value	Unit
Storage junction temperature range		T _{stg}	-40-150	℃
Operating junction temperature range		T _j	-40-125	℃
Repetitive peak off-state voltage (T _j =25℃)		V _{DRM}	800	V
Repetitive peak reverse voltage (T _j =25℃)		V _{RRM}	800	V
RMS on-state current (T _c ≤44℃)		I _{T(RMS)}	1	A
Non repetitive surge peak on-state current (full cycle , t _p =20ms , T _j =25℃)		I _{TSM}	16.5	A
Non repetitive surge peak on-state current (full cycle , t _p =16.6ms , T _j =25℃)			18	
I ² t value for fusing (t _p =10ms , T _j =25℃)		I ² t	1.36	A ² s
Critical rate of rise of on-state current (I _G =2×I _{GT} , f=100Hz , T _j =125℃)	I - II -III	di/dt	50	A/μs
	IV		30	
Peak gate current (t _p =20μs , T _j =125℃)		I _{GM}	2	A
Average gate power dissipation (T _j =125℃)		P _{G(AV)}	0.5	W
Peak gate power		P _{GM}	5	W

Peak pulse voltage ($T_J=25^{\circ}\text{C}$; non-repetitive, off-state; FIG.7)	V_{PP}	4	kV
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ELECTRICAL CHARACTERISTICS ($T_J=25^{\circ}\text{C}$ unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I_{GT}	$V_D=12\text{V}$ $R_L=33\Omega$	I - II -III	MAX.	5	mA
		IV		10	
V_{GT}		ALL	MAX.	1.3	V
V_{GD}	$V_D=V_{DRM}$ $T_J=125^{\circ}\text{C}$ $R_L=3.3\text{K}\Omega$	ALL	MIN.	0.2	V
I_L	$I_G=1.2I_{GT}$	I -III-IV	MAX.	5	mA
		II		20	
I_H	$I_T=50\text{mA}$		MAX.	7	mA
dV/dt	$V_D=540\text{V}$ Gate Open $T_J=110^{\circ}\text{C}$		MIN.	300	$\text{V}/\mu\text{s}$
$(dV/dt)_c$	$(dI/dt)_c=0.44\text{A/ms}$, $T_J=110^{\circ}\text{C}$		MIN.	3	$\text{V}/\mu\text{s}$
t_{on}	$I_G=20\text{mA}$ $I_A=200\text{mA}$ $I_R=20\text{mA}$ $T_J=25^{\circ}\text{C}$		TYP.	2.5	μs
t_{off}				25	

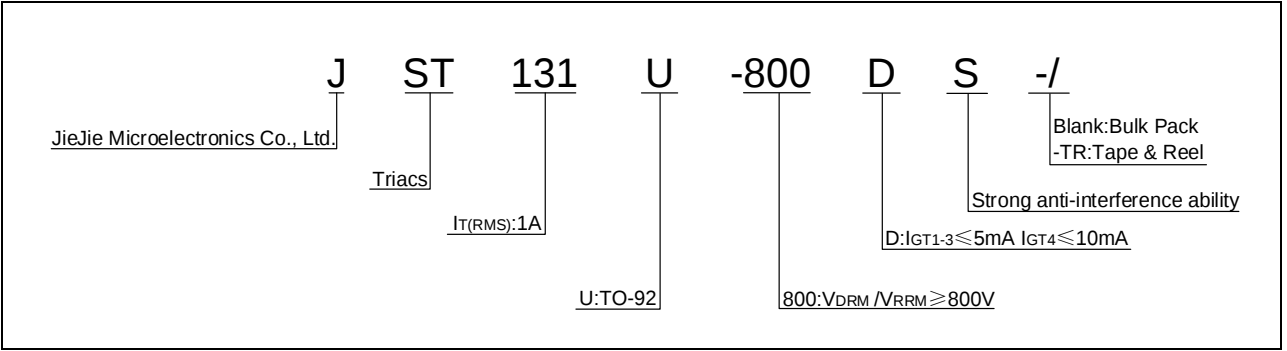
STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX.)	Unit
V_{TM}	$I_{TM}=1.4\text{A}$ $t_p=380\mu\text{s}$	$T_J=25^{\circ}\text{C}$	1.45	V
V_{TO}	Threshold voltage	$T_J=125^{\circ}\text{C}$	0.96	V
R_D	Dynamic resistance	$T_J=125^{\circ}\text{C}$	225	$\text{m}\Omega$
I_{DRM}	$V_D=V_{DRM}$ $V_R=V_{RRM}$	$T_J=25^{\circ}\text{C}$	5	μA
I_{RRM}		$T_J=125^{\circ}\text{C}$	0.25	mA

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case (AC)	60	$^{\circ}\text{C}/\text{W}$
$R_{th(j-a)}$	junction to ambient (AC)	150	$^{\circ}\text{C}/\text{W}$

ORDERING INFORMATION



MARKING

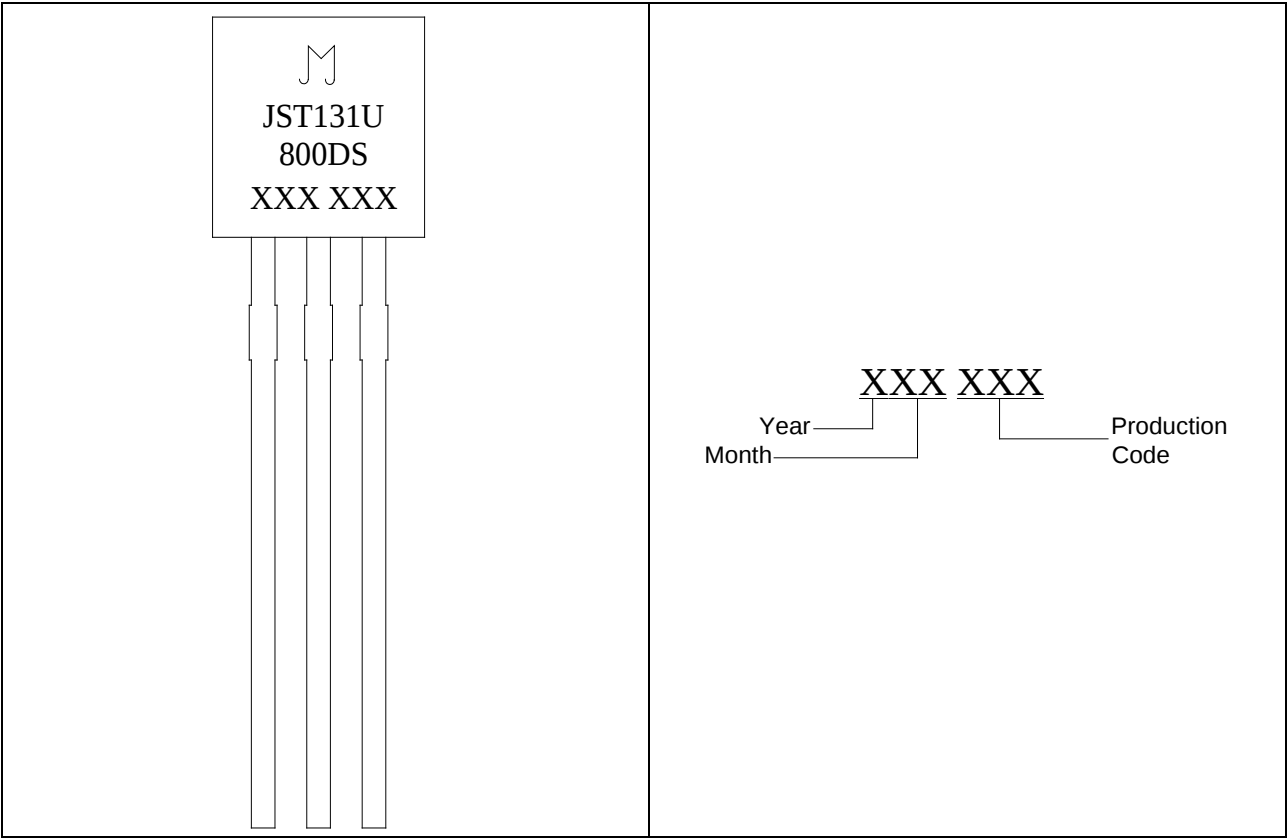


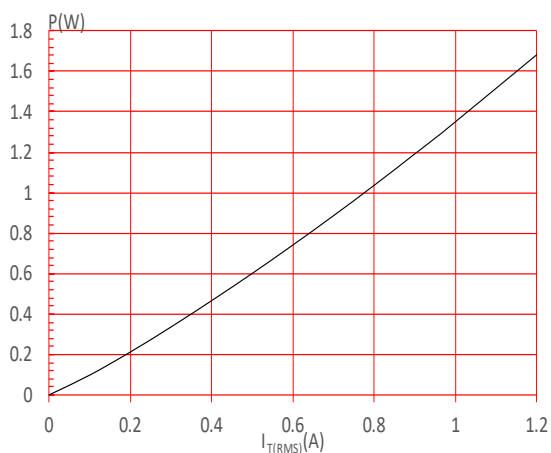
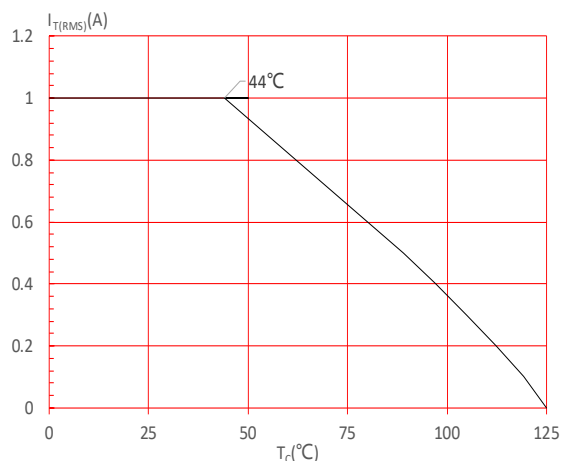
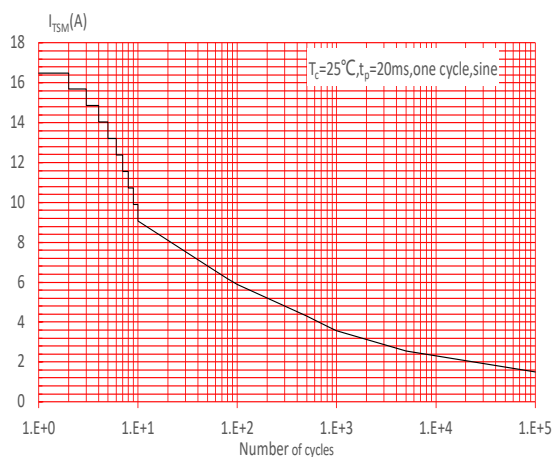
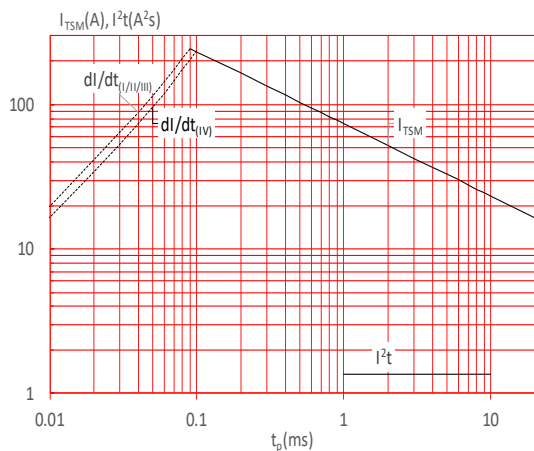
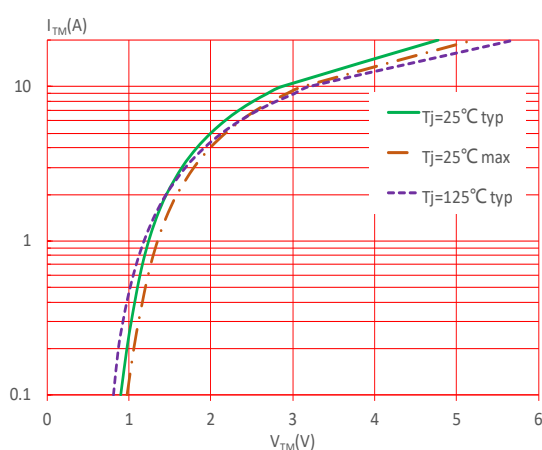
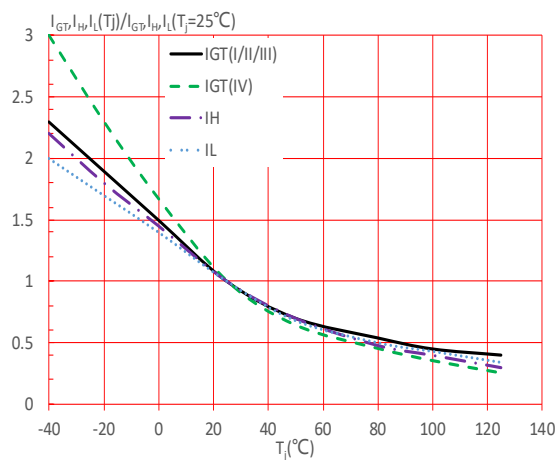
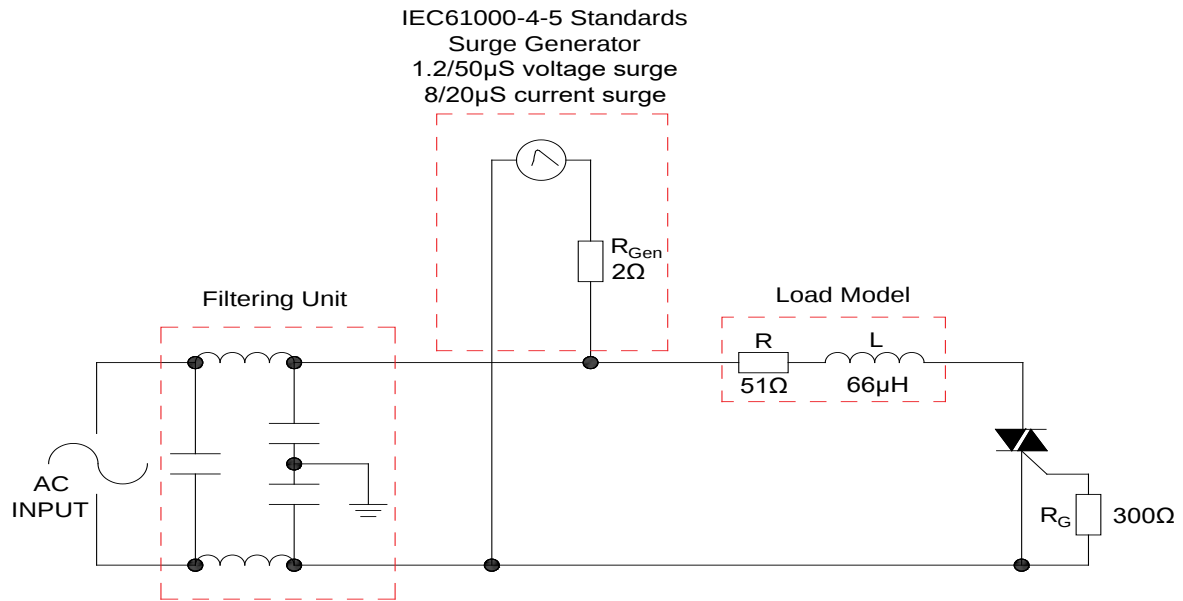
FIG.1: Maximum power dissipation versus RMS on-state current**FIG.2:** RMS on-state current versus case temperature**FIG.3:** Surge peak on-state current versus number of cycles**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20ms$, and corresponding value of I^2t (I - II - III: $di/dt < 50A/\mu s$; IV: $di/dt < 30A/\mu s$)**FIG.4:** On-state characteristics**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature

FIG.7: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



LEAD FORMING AND SOLDERING

Refer to the application note “Assembly Instructions for Thyristors in Through-hole Package” released by JieJie Microelectronics

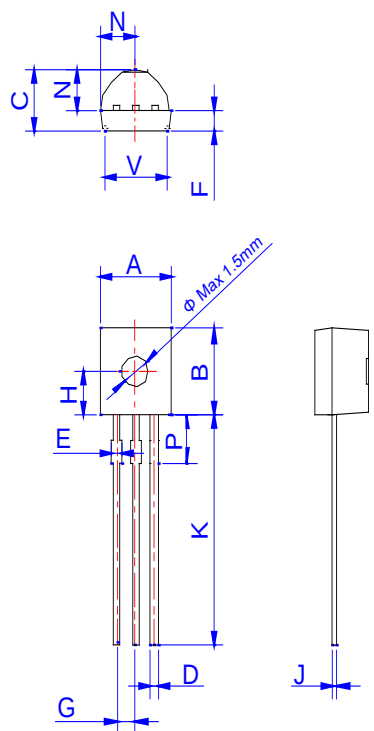
ORDERING INFORMATION

Order code	Voltage $V_{\text{DRM}}/V_{\text{RRM}}$ (V)	IGT(mA)		Package	Base qty. (pcs)	Delivery mode
		I - II - III	IV			
JST131U-800DS	800	5	10	TO-92	1,000	Bulk Pack
JST131U-800DS-TR					2,000	Tape & Reel

Document Revision History

Date	Revision	Changes
Jan.23, 2023	A.1.0	Last updated
Mar.31, 2025	A.2.0	Renew PACKAGE MECHANICAL DATA

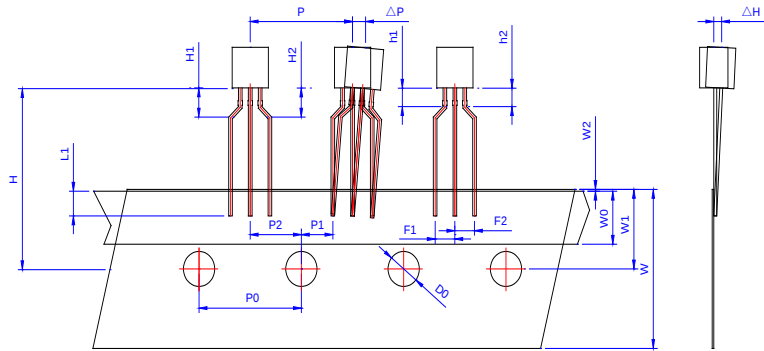
PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.45		5.20	0.175		0.205
B	4.32		5.33	0.170		0.210
C	3.18		4.19	0.125		0.165
D	0.407		0.533	0.016		0.021
E	0.50		0.70	0.020		0.028
F	1.10		1.30			0.051
G	1.10		1.40	0.043		0.055
H	2.20		2.40	0.087		0.094
J	0.36		0.50	0.014		0.020
K	12.70		15.0	0.500		0.591
N	2.04		2.66	0.080		0.105
P	1.80		2.30	0.071		0.091
V	4.10		4.50	0.161		0.177

DELIVERY MODE

PACKAGE	OUTLINE	BAG (PCS)	INNER BOX (PCS)	CARTON BOX (PCS)
TO-92	Bulk Pack	1,000	10,000	50,000



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
P	12.40	12.70	13.00	0.488	0.500	0.512
P0	12.40	12.70	13.00	0.488	0.500	0.512
P1	3.55	3.85	4.15	0.140	0.152	0.163
P2	5.95	6.35	6.75	0.233	0.250	0.265
ΔP	-1.00	0	1.00	-0.039	0	0.039
F1、F2	2.30	2.50	2.70	0.090	0.098	0.106
F1-F2	-0.10	0	0.10	-0.004	0	0.004
W	17.50	18.00	19.00	0.689	0.709	0.748
W0	5.50	6.00	6.50	0.217	0.236	0.256
W1	8.50	9.00	9.50	0.335	0.354	0.374
W2			1.00			0.039
D0	3.80	4.00	4.20	0.150	0.157	0.165
ΔH	-1.00	0	1.00	-0.039	0	0.039
L1	2.50			0.098		
H	18.00	19.00	20.00	0.709	0.748	0.787
H1、H2			3.00			0.119
H1-H2	-0.50		0.50	-0.020		0.020
h1、h2			1.00			0.040
h1-h2	-0.20		0.20	-0.008		0.008

PACKAGE	OUTLINE	REEL (PCS)	INNER BOX (PCS)	CARTON BOX (PCS)
TO-92	Tape & Reel	/	2,000	20,000

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